LH5324500

CMOS 24M (3M × 8/1.5M × 16) MROM

FEATURES

- 3,145,728 words × 8 bit organization
  (Byte mode)
  1,572,864 words × 16 bit organization
  (Word mode)
- Access time: 150 ns (MAX.)
- Power consumption:
  Operating: 357.5 mW (MAX.)
  Standby: 550 µW (MAX.)
- Static operation
- TTL compatible I/O
- Three-state outputs
- Single +5 V power supply
- Package: 44-pin, 600-mil SOP

DESCRIPTION

The LH5324500 is a 24M-bit mask-programmable ROM organized as 3,145,728 × 8 bits (Byte mode) or 1,572,864 × 16 bits (Word mode) that can be selected by a $\overline{\text{BYTE}}$ input pin. It is fabricated using silicon-gate CMOS process technology.

PIN CONNECTIONS

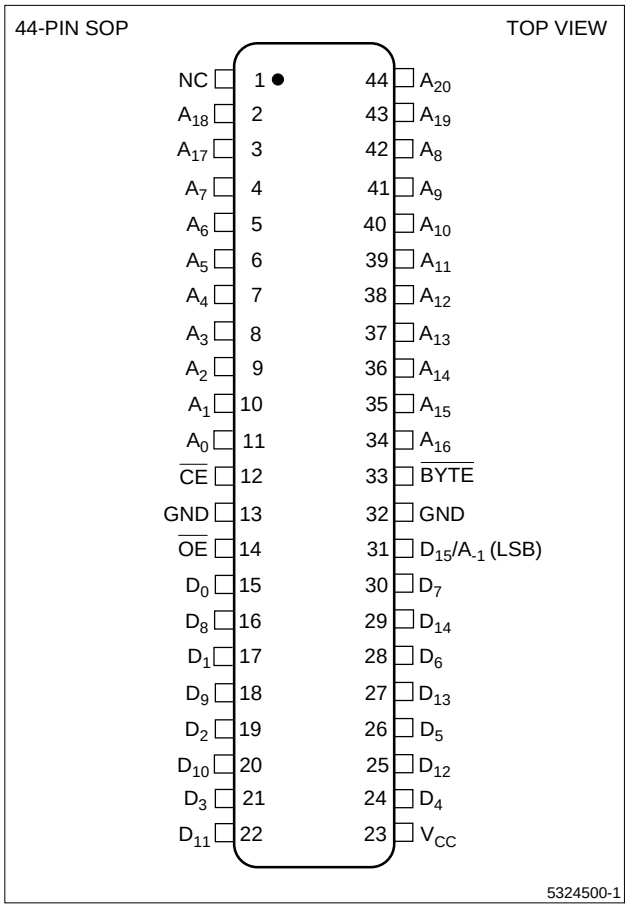


Figure 1. Pin Connections for SOP Package

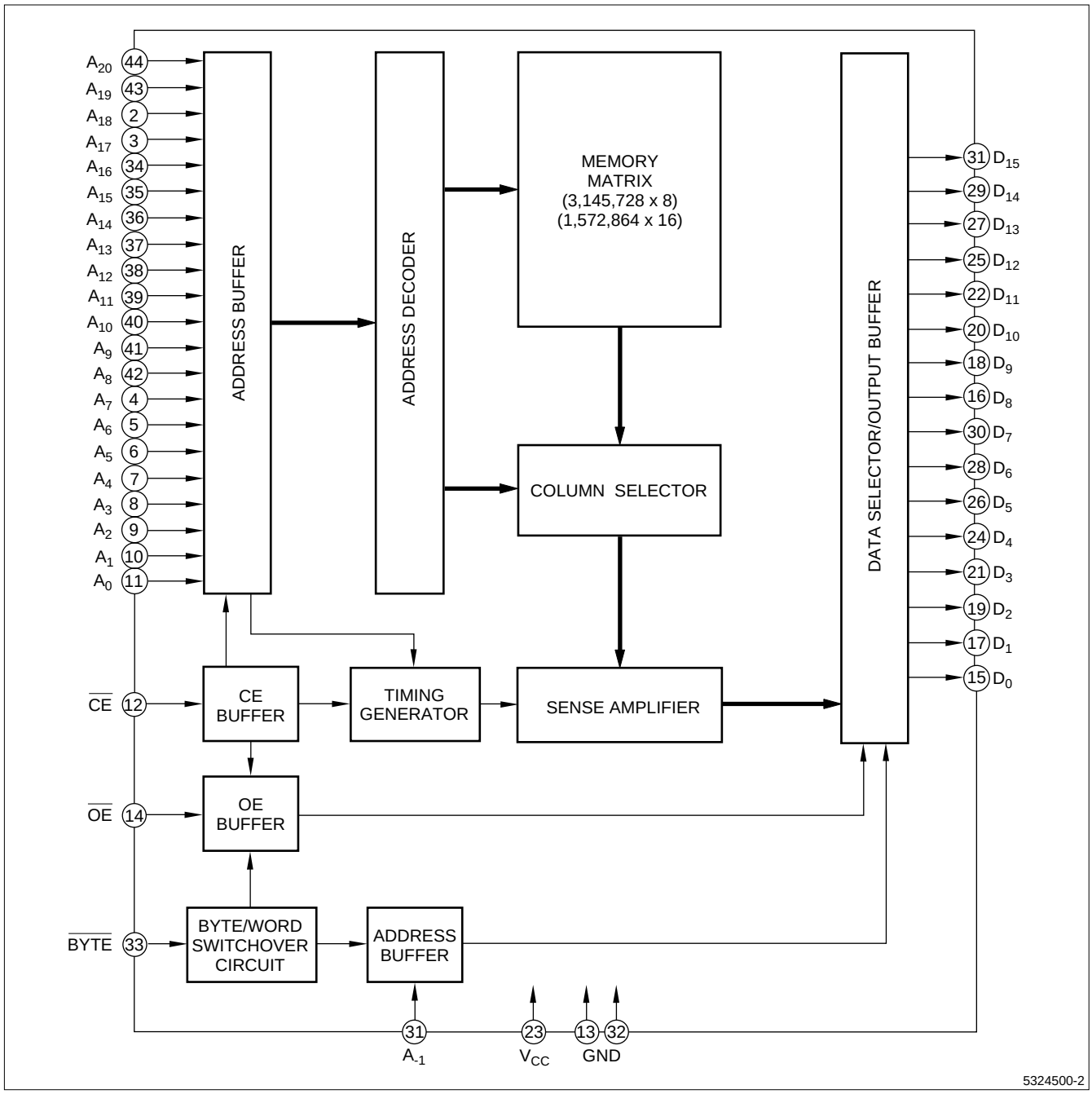


Figure 2. LH5324500 Block Diagram

PIN DESCRIPTION

SIGNAL	PIN NAME	NOTE
$A_{-1} - A_{20}$	Address input	1
$D_0 - D_{15}$	Data output	1
$\overline{BYTE}$	Byte/word mode switch	1
$\overline{CE}$	Chip Enable input	

SIGNAL	PIN NAME	NOTE
$\overline{OE}$	Output Enable input	
V_{CC}	Power supply (+5 V)	
GND	Ground	
NC	No connection	

NOTE:

1. The D_{15}/A_{-1} pin becomes LSB address input (A_{-1}) when the $\overline{BYTE}$ pin is set to be LOW in byte mode, and data output (D_{15}) when set to be HIGH in word mode. When the address inputs become 'High' to both A_{19} and A_{20}, the data outputs become 'Unspecified' since the data does not exist in this address area.

TRUTH TABLE

$\overline{CE}$	$\overline{OE}$	$\overline{BYTE}$	A_{-1} (D_{15})	DATA OUTPUT		ADDRESS INPUT		SUPPLY CURRENT
				$D_0 – D_7$	$D_8 – D_{15}$	LSB	MSB	
H	X	X	X	High-Z	High-Z	–	–	Standby (I_{SB})
L	H	X	X	High-Z	High-Z	–	–	Operating (I_{CC})
L	L	H	–	$D_0 – D_7$	$D_8 – D_{15}$	A_0	A_{20}	Operating (I_{CC})
L	L	L	L	$D_0 – D_7$	High-Z	A_{-1}	A_{20}	Operating (I_{CC})
L	L	L	H	$D_8 – D_{15}$	High-Z	A_{-1}	A_{20}	Operating (I_{CC})

NOTE:

X = H or L; High-Z = High-impedance

The D_{15}/A_{-1} pin becomes LSB address input (A_{-1}) when the $\overline{BYTE}$ pin is set to be LOW in byte mode, and data output (D_{15}) when set to be HIGH in word mode. When the address input at both A_{19} and A_{20} is HIGH level, the data outputs become high-impedance because this data does not have data.

TRUTH TABLE WHEN BOTH A_{20} ADN A_{19} ARE HIGH

$\overline{CE}$	$\overline{OE}$	$\overline{BYTE}$	A_{-1} (D_{15})	A_{20}	A_{19}	DATA OUTPUT		ADDRESS INPUT		SUPPLY CURRENT
						$D_0 – D_7$	$D_8 – D_{15}$	LSB	MSB	
H	X	X	X	X	X	High-Z	High-Z	–	–	Standby (I_{SB})
L	X	H	–	H	H	High-Z	High-Z	A_0	A_{20}	Operating (I_{CC})
L	X	H	–	H	H	High-Z	High-Z	A_{-1}	A_{20}	Operating (I_{CC})

NOTE:

X = H or L; High-Z = High-impedance

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply voltage	V_{CC}	–0.3 to +7.0	V
Input voltage	V_{IN}	–0.3 to V_{CC} + 0.3	V
Output voltage	V_{OUT}	–0.3 to V_{CC} + 0.3	V
Operating temperature	Topr	0 to +70	°C
Storage temperature	Tstg	–65 to +150	°C

RECOMMENDED OPERATING CONDITIONS (T_A = 0°C to +70°C)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply voltage	V_{CC}	4.5	5.0	5.5	V

DC CHARACTERISTICS (V_{CC} = 5 V ±10%, T_A = 0°C to +70°C)

PARAMETER	SYMBOL	CONDITIONS	MIN.	MAX.	UNIT	NOTE
Input 'High' voltage	V_{IH}		2.2	V_{CC} + 0.3	V	
Input 'Low' voltage	V_{IL}		–0.3	0.8	V	
Output 'High' voltage	V_{OH}	I_{OH} = –400 µA	2.4		V	
Output 'Low' voltage	V_{OL}	I_{OL} = 2.0 mA		0.4	V	
Input leakage current	$\lvert I_{LI} \rvert$	V_{IN} = 0 V to V_{CC}		10	µA	
Output leakage current	$\lvert I_{LO} \rvert$	V_{OUT} = 0 V to V_{CC}		10	µA	1
Operating current	I_{CC1}	t_{RC} = 150 ns		65	mA	2
	I_{CC2}	t_{RC} = 1 µs		55		
Standby current	I_{SB1}	$\overline{CE}$ = V_{IH}		2	mA	
	I_{SB2}	$\overline{CE}$ = V_{CC} – 0.2 V		100	µA	
Input capacitance	C_{IN}	f = 1 MHz		10	pF	
Output capacitance	C_{OUT}	T_A = 25°C		10	pF	

NOTES:

1. $\overline{CE/OE}$ = V_{IH}
2. V_{IN} = V_{IH} or V_{IL}, $\overline{CE}$ = V_{IL}, outputs open

AC CHARACTERISTICS (V_{CC} = 5 V ±10%, T_A = 0°C to +70°C)

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	NOTE
Read cycle time	t_{RC}	150		ns	
Address access time	t_{AA}		150	ns	
Chip enable access time	t_{ACE}		150	ns	
Output enable delay time	t_{OE}		70	ns	
Output hold time	t_{OH}	5		ns	
Output floating time	t_{CHZ}		60	ns	1
	t_{OHZ}		60	ns	
	t_{AHZ}		70	ns	

NOTE:
1. This is the time required for the outputs to become high-impedance.

AC TEST CONDITIONS

PARAMETER	RATING
Input voltage amplitude	0.6 V to 2.4 V
Input signal rise/fall time	10 ns
Input reference level	1.5 V
Output reference level	0.8 V and 2.2 V
Output load condition	1TTL + 100 pF

CAUTION

To stabilize the power supply, it is recommended that a high-frequency bypass capacitor be connected between the V_{CC} pin and the GND pin.

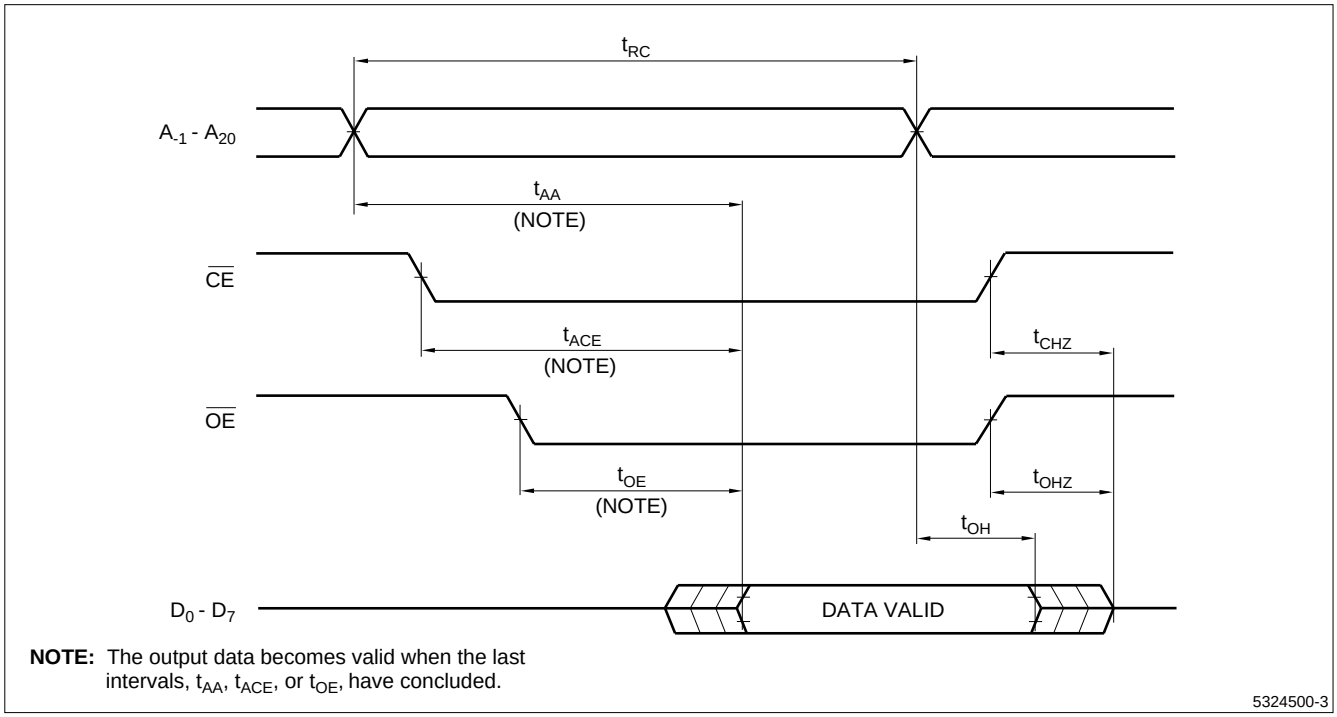


Figure 3. Byte Mode ($\overline{BYTE}$ = V_{IL})

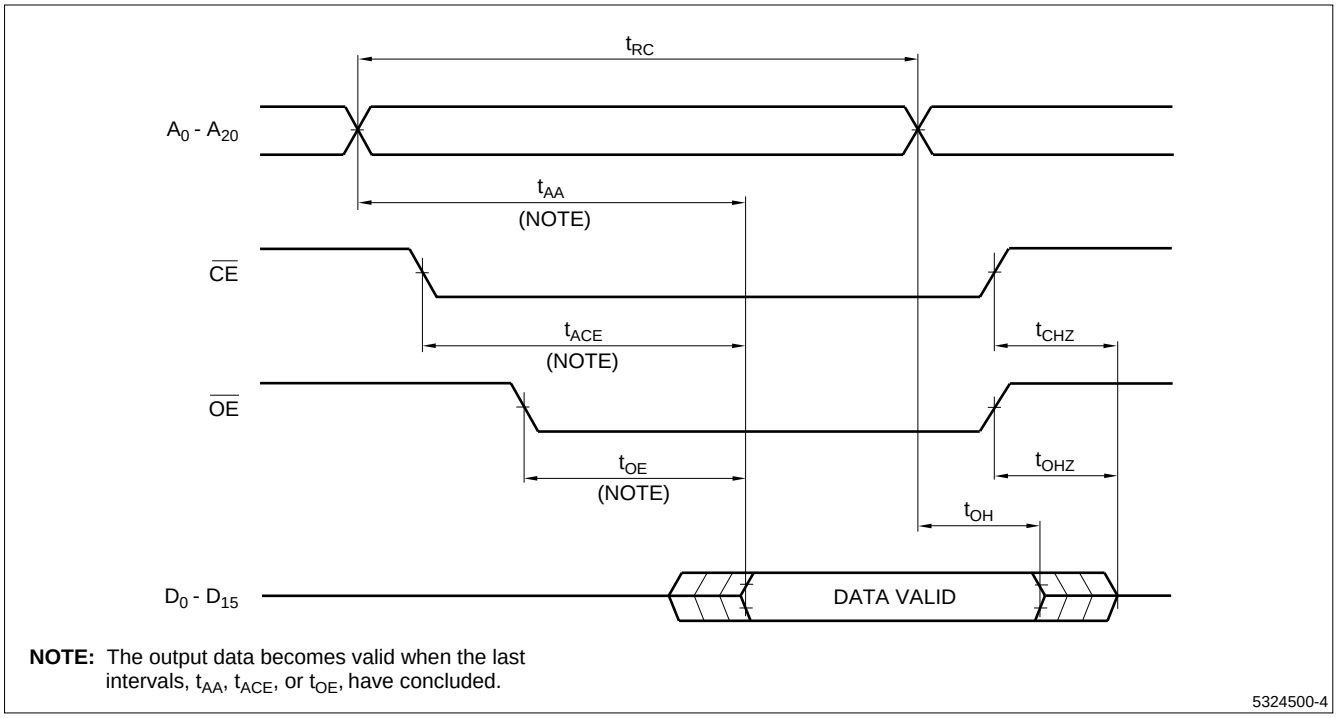


Figure 4. Word Mode ($\overline{BYTE}$ = V_{IH})

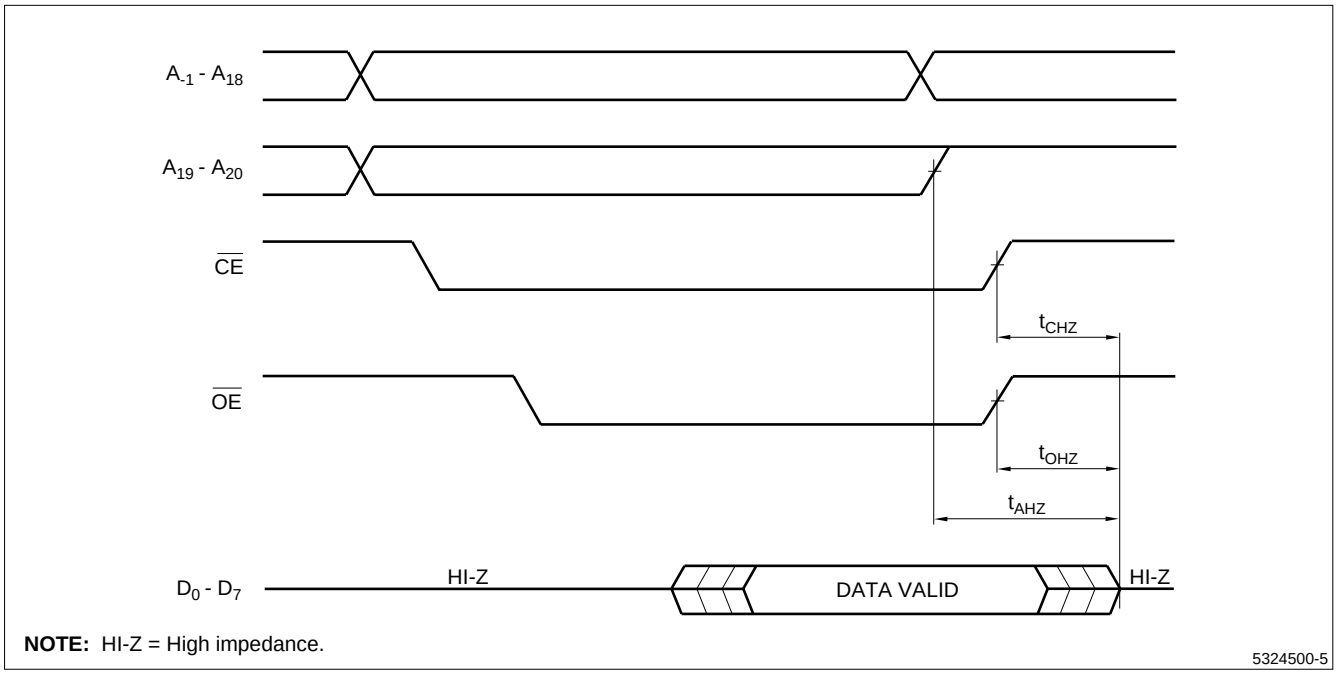


Figure 5. Byte Mode ($\overline{BYTE}$ = V_{IL})
When the address inputs become 'High' to both A_{19} and A_{20}

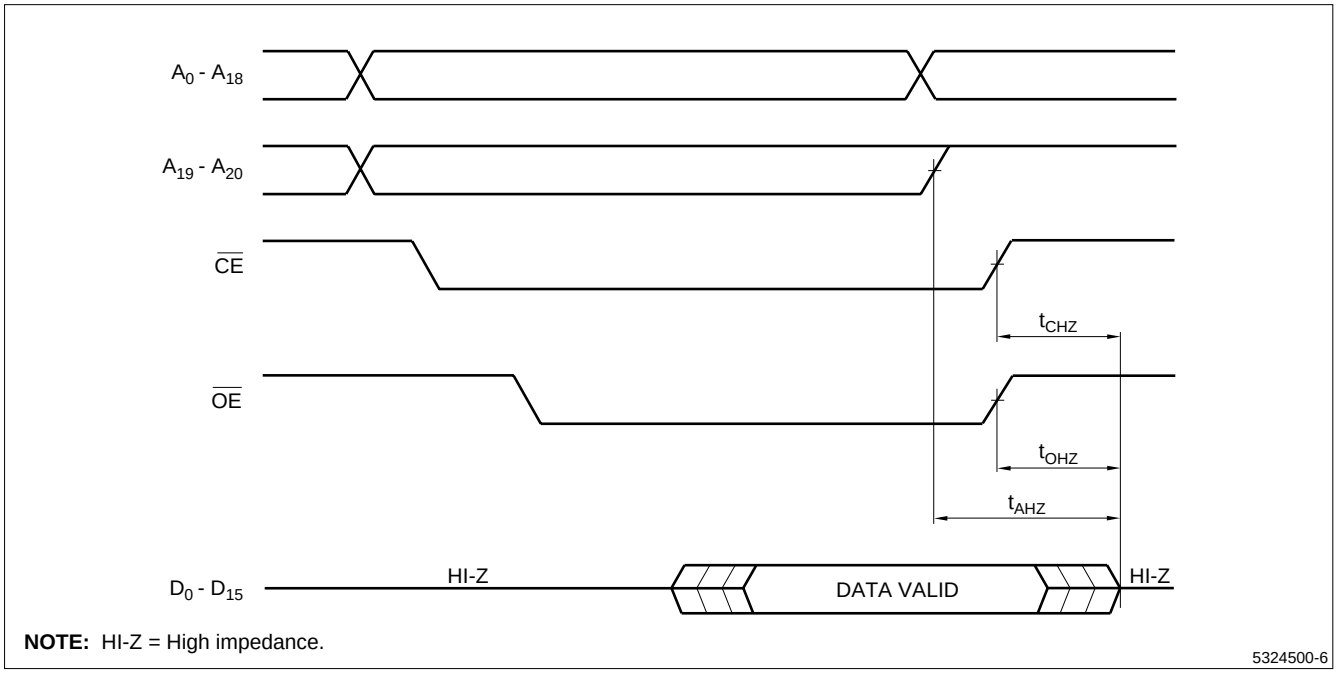
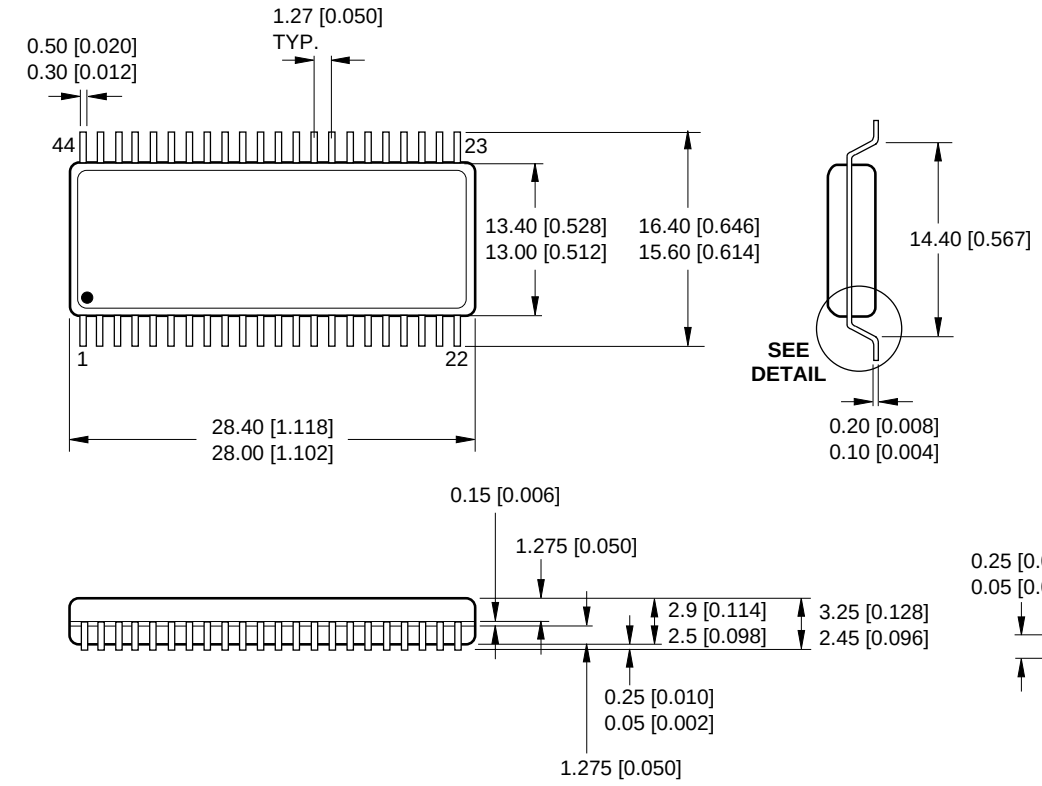


Figure 6. Word Mode ($\overline{BYTE}$ = V_{IH})
When the address inputs become 'High' to both A_{19} and A_{20}

PACKAGE DIAGRAM

44SOP (SOP044-P-0600)



44-pin, 600-mil SOP

ORDERING INFORMATION